onsemi

Gate Drive Optocoupler, High Noise Immunity, 2.5 A Output Current

FOD3120

Description

The FOD3120 is a 2.5 A Output Current Gate Drive Optocoupler, capable of driving most medium power IGBT/MOSFET. It is ideally suited for fast switching driving of power IGBT and MOSFETs used in motor control inverter applications, and high performance power system.

It utilizes **onsemi's** coplanar packaging technology, OPTOPLANAR[®], and optimized IC design to achieve high noise immunity, characterized by high common mode rejection.

It consists of a gallium aluminum arsenide (AlGaAs) light emitting diode optically coupled to an integrated circuit with a high-speed driver for push-pull MOSFET output stage.

Features

- High Noise Immunity Characterized by 35 kV/µs Minimum Common Mode Rejection
- 2.5 A Peak Output Current Driving Capability for Most 1200 V/20 A IGBT
- Use of P-Channel MOSFETs at Output Stage Enables Output Voltage Swing Close to the Supply Rail
- Wide Supply Voltage Range from 15 V to 30 V
- Fast Switching Speed
 - 400 ns maximum Propagation Delay
 - 100 ns maximum Pulse Width Distortion
- Under Voltage LockOut (UVLO) with Hysteresis
- Extended Industrial Temperate Range, -40°C to 100°C Temperature Range
- Safety and Regulatory Approvals
 - UL1577, 5000 V_{RMS} for 1 min.
 - DIN EN/IEC60747-5-5
- $R_{DS(ON)}$ of 1 Ω (typ.) Offers Lower Power Dissipation
- >8.0 mm Clearance and Creepage Distance (Option 'T' or 'TS')
- 1414 V Peak Working Insulation Voltage (VIORM)
- This is a Pb–Free Device

Applications

- Industrial Inverter
- Uninterruptible Power Supply
- Induction Heating
- Isolated IGBT/Power MOSFET Gate Drive

Related Resources

- FOD3150, 1 A Output Current, Gate Drive Optocoupler Datasheet
- https://www.onsemi.com/products/optoelectronics/





PDIP8 9.655x6.6, 2.54P CASE 646CQ



PDIP8 GW

CASE 709AC

PDIP8 GW CASE 709AD PDIP8 6.6x3.81, 2.54P CASE 646BW

MARKING DIAGRAM

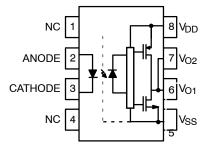


3120 = Device Number

V = DIN_EN/IEC60747-5-5 Option (only

- appears on component ordered with this option)
- XX = Two Digit Year Code
- YY = Two Digit Work Week
- B = Assembly Package Code

FUNCTIONAL BLOCK DIAGRAM



Note: A 0.1 μ F bypass capacitor must be connected between pins 5 and 8.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 14 of this data sheet.

Table 1. TRUTH TABLE

LED	V _{DD} – V _{SS} "Positive Going" (Turn-on)	V _{DD} – V _{SS} "Negative Going" (Turn-off)	vo
Off	0 V to 30 V	0 V to 30 V	Low
On	0 V to 11.5 V	0 V to 10 V	Low
On	11.5 V to 13.5 V	10 V to 12 V	Transition
On	13.5 V to 30 V	12 V to 30 V	High

Table 2. PIN DEFINITIONS

Pin #	Name	Description
1	NC	Not Connected
2	Anode	LED Anode
3	Cathode	LED Cathode
4	NC	Not Connected
5	V _{SS}	Negative Supply Voltage
6	V _{O2}	Output Voltage 2 (internally connected to V _{O1})
7	V _{O1}	Output Voltage 1
8	V _{DD}	Positive Supply Voltage

Table 3. SAFETY AND INSULATION RATINGS

As per DIN EN/IEC 60747–5–5. This optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter		Min.	Тур.	Max.	Unit	
	Installation Classifications per DIN VDE	< 150 V _{RMS}		I–IV	I–IV		
	0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}		I–IV			
		< 450 V _{RMS}		_			
		< 600 V _{RMS}		-			
		< 1000 V _{RMS} (Option T, TS)		I—III			
	Climatic Classification			40/100/21			
	Pollution Degree (DIN VDE 0110/1.89)			2			
CTI	Comparative Tracking Index		175				
V _{PR}	Input to Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC		2262			Vpeak	
	Input to Output Test Voltage, Method B, $V_{IORM} \times 1.87$ 100% Production Test with $t_m = 1$ s, Partial Discharg		2651			Vpeak	
V _{IORM}	Maximum Working Insulation Voltage		1414			Vpeak	
V _{IOTM}	Highest Allowable Over Voltage		6000			Vpeak	
	External Creepage		8.0			mm	
	External Clearance		7.4			mm	
	External Clearance (for Option T or TS, 0.4" Lead Sp	bacing)	10.16			mm	
DTI	Distance Through Insulation (Insulation Thickness)		0.5			mm	
Τ _S	Case Temperature (Note 1)		175		1	°C	
I _{S,INPUT}	Input Current (Note 1)		400			mA	
P _{S,OUTPUT}	Output Power (Duty Factor ≤ 2.7 %) (Note 1)		700			mW	
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)		10 ⁹			Ω	

1. Safety limit value - maximum values allowed in the event of a failure.

Symbol	Parameter	Value	Units
T _{STG}	Storage Temperature	–55 to +125	°C
T _{OPR}	Operating Temperature	-40 to +100	°C
TJ	Junction Temperature	-40 to +125	°C
T _{SOL}	Lead Wave Solder Temperature (refer to page 13 for reflow solder profile)	260 for 10 s	°C
I _{F(AVG)}	Average Input Current	25	mA
I _{F(Peak)}	Peak Transient Forward Current (Note 2)	1	А
f	Operating Frequency (Note 3)	50	kHz
V _R	Reverse Input Voltage	5	V
I _{O(PEAK)}	Peak Output Current (Note 4)	3.0	А
$V_{DD} - V_{SS}$	Supply Voltage	0 to 35	V
	$T_A \ge 90$	0°C 0 to 30	
V _{O(PEAK)}	Peak Output Voltage	0 to V _{DD}	V
t _{R(IN)} , t _{F(IN)}	Input Signal Rise and Fall Time	500	ns
PDI	Input Power Dissipation (Note 5, Note 7)	45	mW
PDo	Output Power Dissipation (Note 6, Note 7)	250	mW

Table 4. ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise specified.)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Pulse Width, PW $\leq 1 \ \mu$ s, 300 pps 3. Exponential Waveform, $I_{O(PEAK)} \leq |2.5 \ A| \ (\leq 0.3 \ \mu$ s) 4. Maximum pulse width = 10 \ \mus, maximum duty cycle = 1.1% 5. Derate linearly above 87°C, free air temperature at a rate of 0.77 mW/°C

6. No derating required across temperature range.

7. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

Table 5. RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Units
T _A	Ambient Operating Temperature	-40 to +100	°C
$V_{DD} - V_{SS}$	Power Supply	15 to 30	V
I _{F(ON)}	Input Current (ON)	7 to 16	mA
V _{F(OFF)}	Input Voltage (OFF)	0 to 0.8	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 6. ISOLATION CHARACTERISTICS

Apply over all recommended conditions, typical value is measured at T_A = 25°C

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{ISO}	Input-Output Isolation Voltage	T_{A} = 25°C, R.H.< 50 %, t = 1.0 min., $I_{I-O} \leq$ 10 $\mu A,$ 50 Hz (Note 8, Note 9)	5000			V _{RMS}
R _{ISO}	Isolation Resistance	V _{I-O} = 500 V (Note 8)		10 ¹¹		Ω
C _{ISO}	Isolation Capacitance	$V_{I-O} = 0$ V, Frequency = 1.0 MHz (Note 8)		1		pF

8. Device is considered a two terminal device: pins 2 and 3 are shorted together and pins 5, 6, 7 and 8 are shorted together.

9. 5000 V_{RMS} for 1 minute duration is equivalent to 6000 VAC_{\text{RMS}} for 1 second duration.

Table 7. ELECTRICAL CHARACTERISTICS

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _F	Input Forward Voltage	I _F = 10 mA	1.2	1.5	1.8	V
$\Delta(V_{\rm F}/T_{\rm A})$	Temperature Coefficient of Forward Voltage			-1.8		mV/°C
BV _R	Input Reverse Breakdown Voltage	I _R = 10 μA	5			V
C _{IN}	Input Capacitance	f = 1 MHz, V _F = 0 V		60		pF
I _{OH}	High Level Output Current	$V_{O} = V_{DD} - 3 V$	-1.0	-2.0	-2.5	Α
	(Note 3)	$V_{O} = V_{DD} - 6 V$	-2.0		-2.5	
I _{OL}	Low Level Output Current	V _O = V _{SS} + 3 V	1.0	2.0	2.5	Α
	(Note 3)	$V_{O} = V_{SS} + 6 V$	2.0		2.5	
V _{OH}	High Level Output Voltage	I _F = 10 mA, I _O = -2.5 A	$V_{DD} - 6.25 V$	V _{DD} – 2.5 V		V
		I _F = 10 mA, I _O = -100 mA	$V_{DD} - 0.25 V$	V _{DD} – 0.1 V		
V _{OL}	Low Level Output Voltage	I _F = 0 mA, I _O = 2.5 A		V _{SS} + 2.5 V	V _{SS} + 6.25 V	V
		I _F = 0 mA, I _O = 100 mA		V _{SS} + 0.1 V	V _{SS} + 0.25 V	
I _{DDH}	High Level Supply Current	V_{O} = Open, I_{F} = 7 to 16 mA		2.8	3.8	mA
I _{DDL}	Low Level Supply Current	V_{O} = Open, V_{F} = 0 to 0.8 V		2.8	3.8	mA
I _{FLH}	Threshold Input Current Low to High	I _O = 0 mA, V _O > 5 V		2.3	5.0	mA
V_{FHL}	Threshold Input Voltage High to Low	I _O = 0 mA, V _O < 5 V	0.8			V
V _{UVLO+}	Under Voltage Lockout	I _F = 10mA, V _O > 5 V	11.5	12.7	13.5	V
V _{UVLO-}	Threshold	I _F = 10 mA, V _O < 5 V	10.0	11.2	12.0	V
UVLO _{HYS}	Under Voltage Lockout Threshold Hysteresis			1.5		V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Table 8. SWITCHING CHARACTERISTICS

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{PHL}	Propagation Delay Time to Logic Low Output	$I_{\rm F} = 7 {\rm mA}$ to 16 mA,	150	275	400	ns
t _{PLH}	Propagation Delay Time to Logic High Output	Rg = 10 Ω, Cg = 10 nF, f = 10 kHz, Duty Cycle = 50 %	150	255	400	ns
PWD	Pulse Width Distortion, t _{PHL} - t _{PLH}			20	100	ns
PDD (Skew)	Propagation Delay Difference Between Any Two Parts or Channels, $(t_{\text{PHL}}-t_{\text{PLH}})$ (Note 10)		-250		250	ns
t _R	Output Rise Time (10% – 90%)			60		ns
t _F	Output Fall Time (90% – 10%)			60		ns
t _{UVLO ON}	UVLO Turn On Delay	l _F = 10 mA , V _O > 5 V		1.6		μs
t _{UVLO OFF}	UVLO Turn Off Delay	l _F = 10 mA , V _O < 5 V		0.4		μs
CM _H	Common Mode Transient Immunity at Output High	$ T_A = 25^{\circ}C, V_{DD} = 30 \text{ V}, \\ I_F = 7 \text{ to } 16 \text{ mA}, V_{CM} = 2000 \text{ V} \\ (\text{Note } 11) $	35	50		kV/μs
CM _L	Common Mode Transient Immunity at Output Low		35	50		kV/μs

The difference between t_{PHL} and t_{PLH} between any two FOD3120 parts under same test conditions.
 Common mode transient immunity at output high is the maximum tolerable negative dVcm/dt on the trailing edge of the common mode

impulse signal, Vcm, to assure that the output will remain high (i.e., V_O > 15.0 V).
12. Common mode transient immunity at output low is the maximum tolerable positive dVcm/dt on the leading edge of the common pulse signal, Vcm, to assure that the output will remain low (i.e., V_O < 1.0 V).

TYPICAL PERFORMANCE CHARACTERISTICS

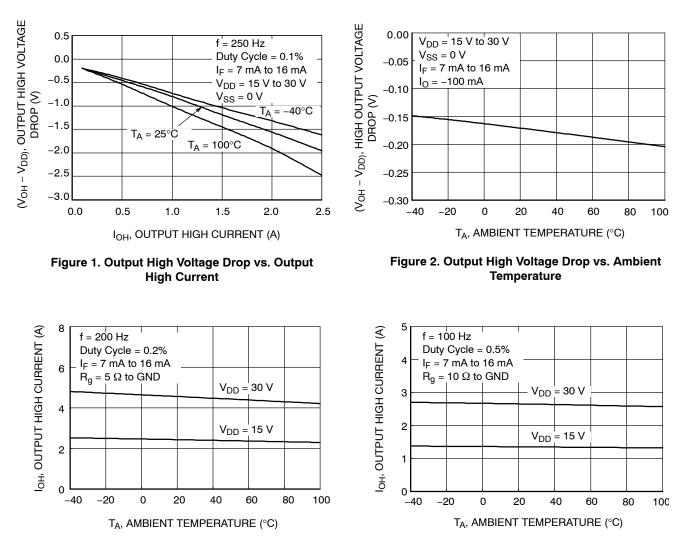
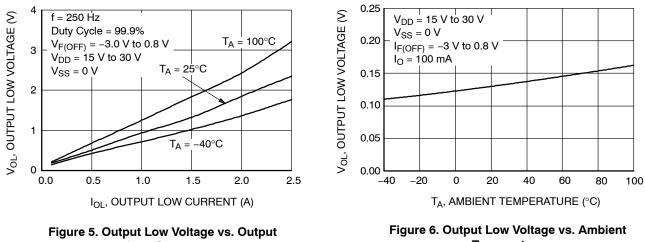
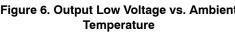


Figure 3. Output High Current vs. Ambient Temperature

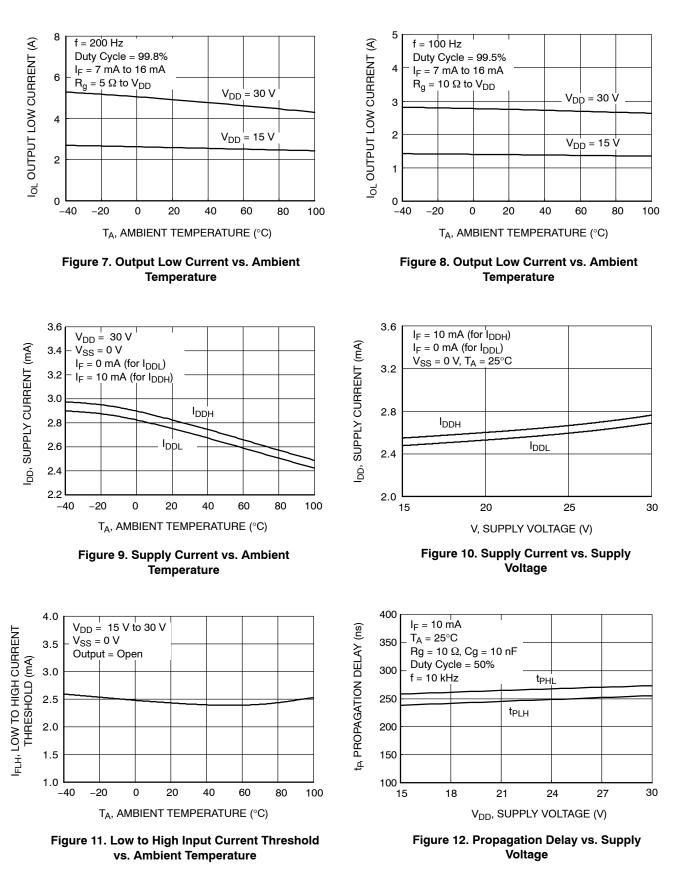
Figure 4. Output High Current vs. Ambient Temperature



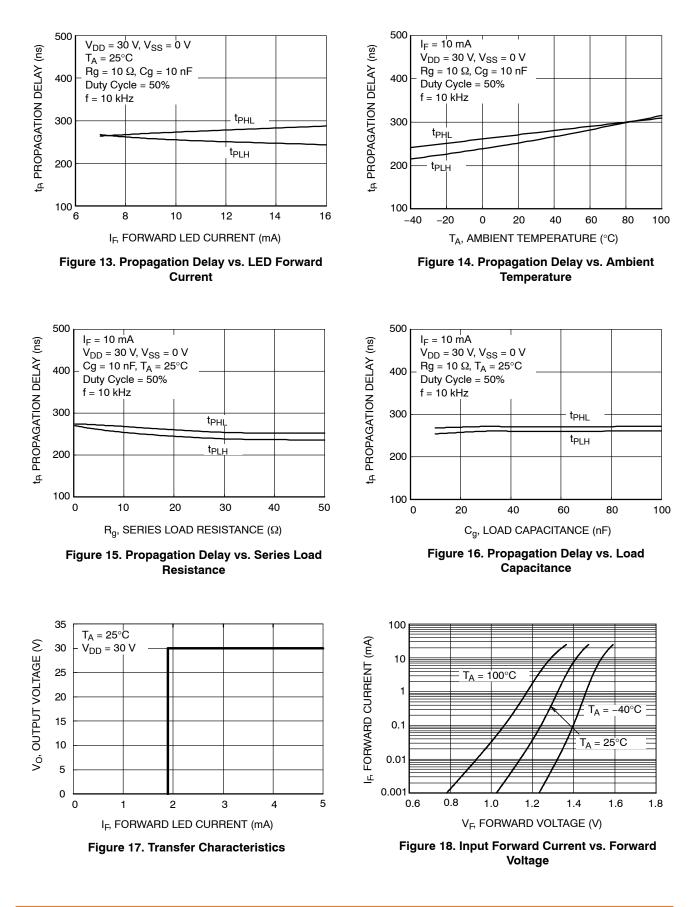
Low Current



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

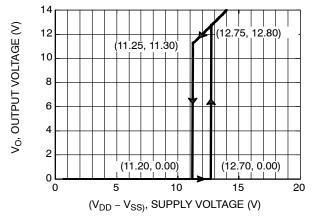
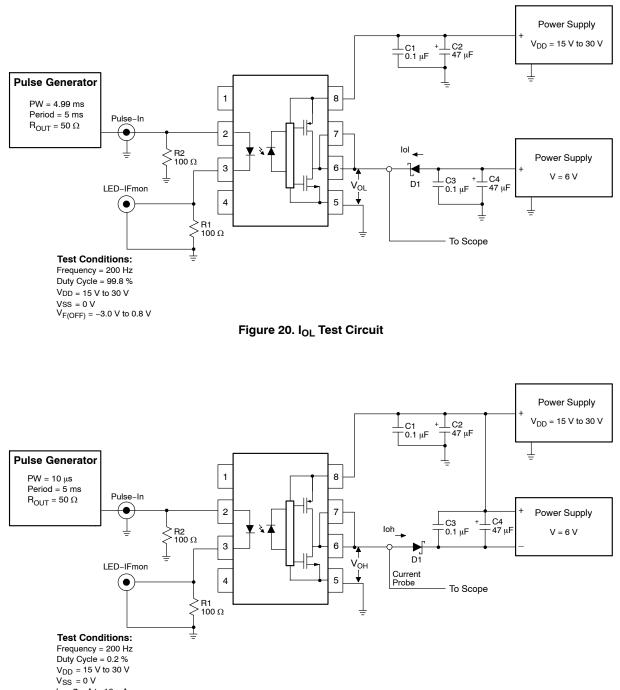


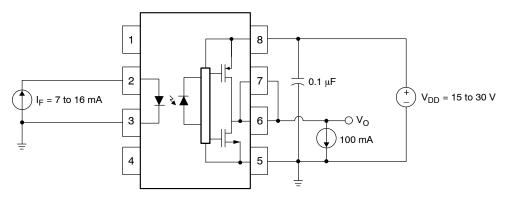
Figure 19. Under Voltage Lockout

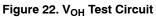
TEST CIRCUIT

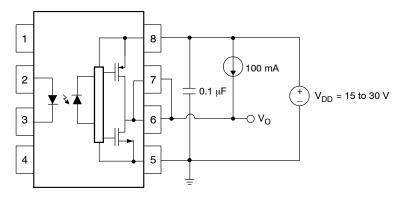


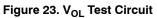
 $I_F = 7 \text{ mA to } 16 \text{ mA}$

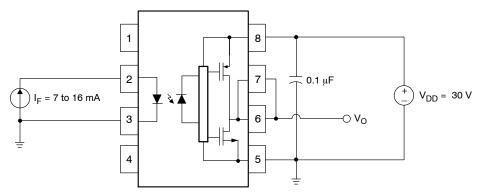














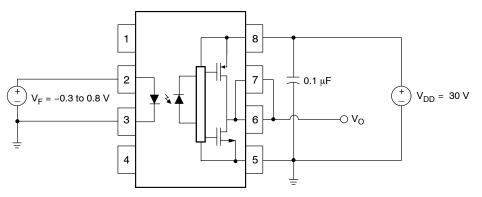
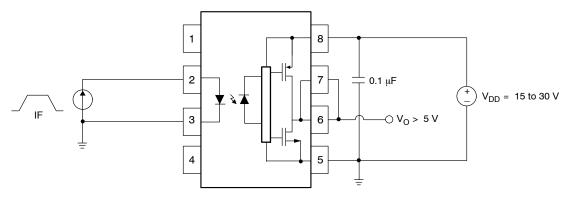
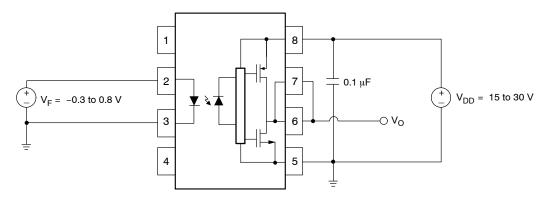


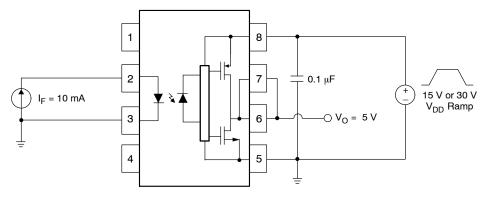
Figure 25. I_{DDL} Test Circuit













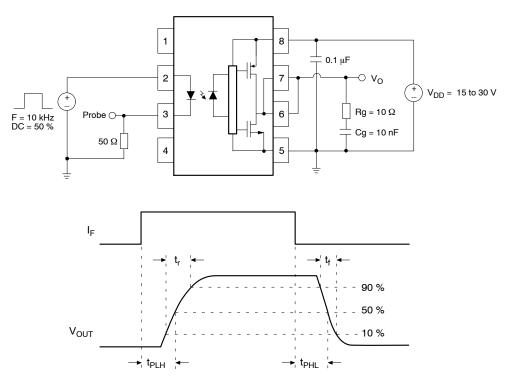
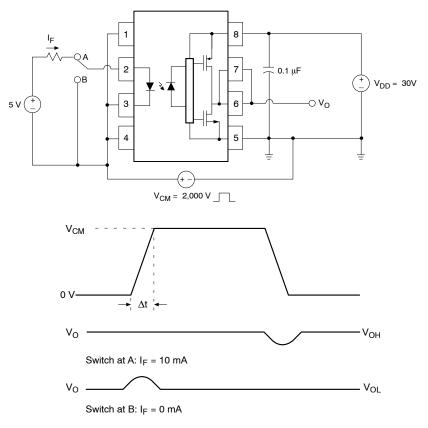


Figure 29. $t_{\text{PHL}}, t_{\text{PLH}}, t_{\text{R}} \text{ and } t_{\text{F}} \text{ Test Circuit and Waveforms}$





REFLOW PROFILE

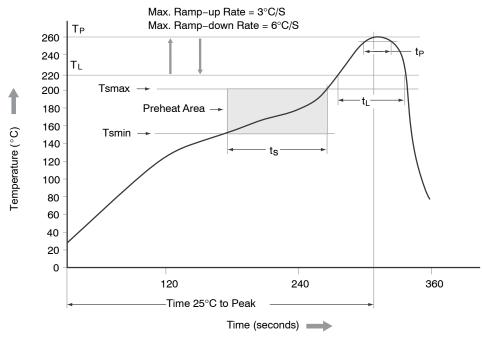


Figure 31. Reflow Profile

Table 9. REFLOW PROFILE

Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t _S) from (Tsmin to Tsmax)	60–120 s
Ramp-up Rate (t _L to t _P)	3°C/s max.
Liquidous Temperature (TL)	217°C
Time (t _L) Maintained Above (T _L)	60–150 s
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 s
Ramp-down Rate (T _P to T _L)	6°C/s max.
Time 25°C to Peak Temperature	8 min. max.

ORDERING INFORMATION

Part Number	Package	Shipping [†]
FOD3120	DIP 8–Pin	50 / Tube
FOD3120S	SMT 8-Pin (Lead Bend)	50 / Tube
FOD3120SD	SMT 8-Pin (Lead Bend)	1000 / Tape & Reel
FOD3120V	DIP 8-Pin, DIN EN/IEC60747-5-5 option	50 / Tube
FOD3120SV	SMT 8-Pin (Lead Bend), DIN EN/IEC60747-5-5 option	50 / Tube
FOD3120SDV	SMT 8-Pin (Lead Bend), DIN EN/IEC60747-5-5 option	1000 / Tape & Reel
FOD3120TV	DIP 8-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 option	50 / Tube
FOD3120TSV	SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 option	50 / Tube
FOD3120TSR2V	SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 option	700 / Tape & Reel

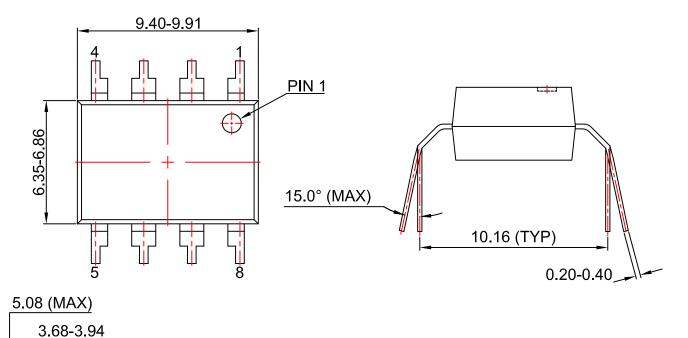
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

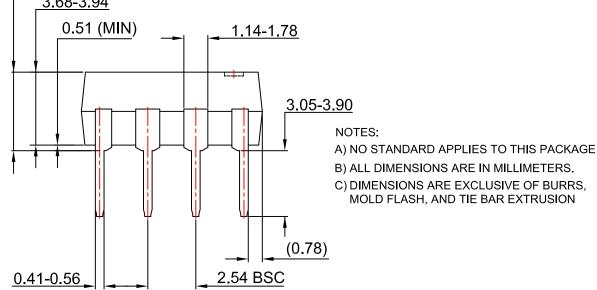
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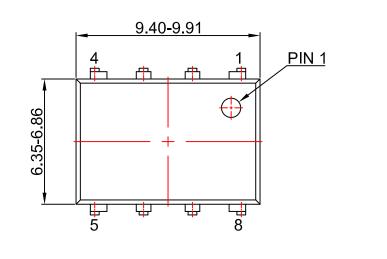
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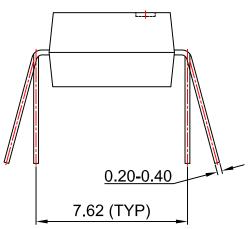
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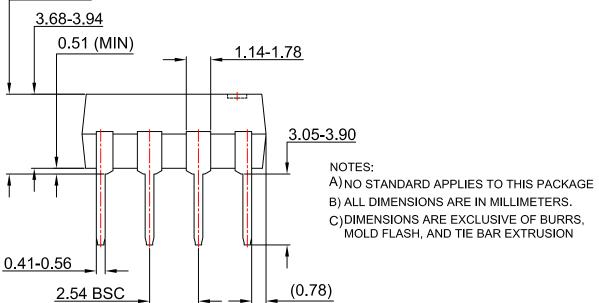
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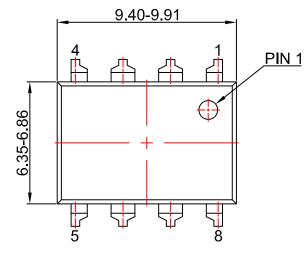


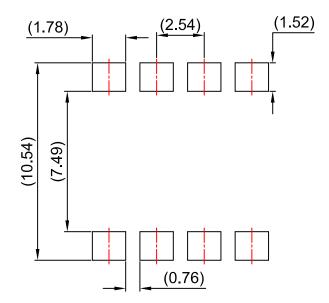
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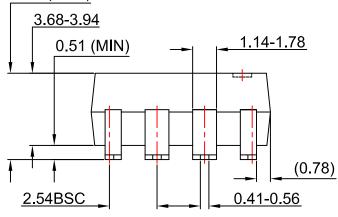
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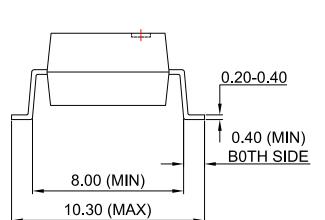
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NOTES:

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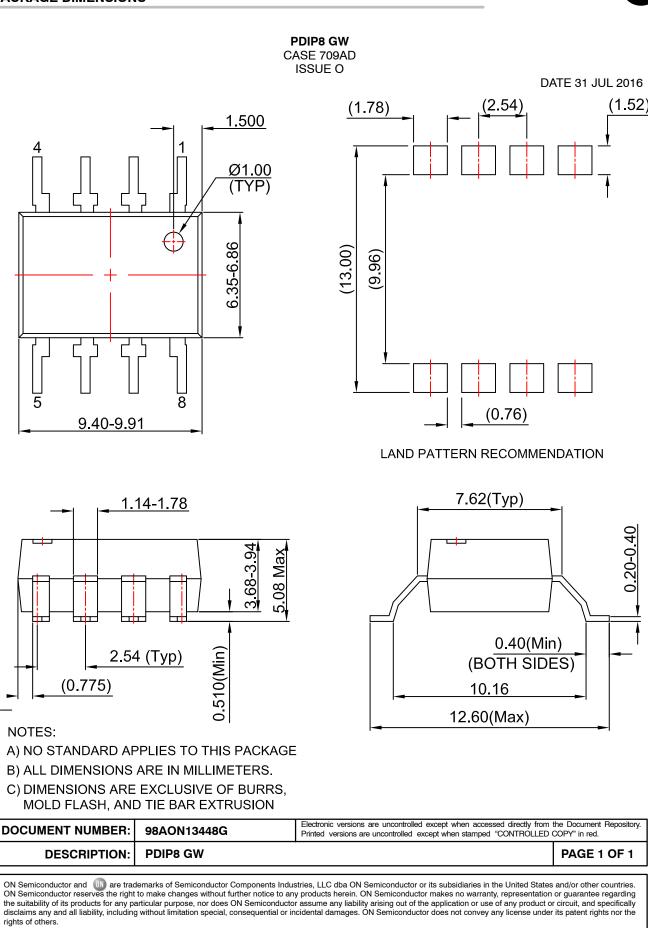
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